



40V P-Channel Enhancement Mode MOSFET

Voltage

-40 V

Current

-50 A

Features

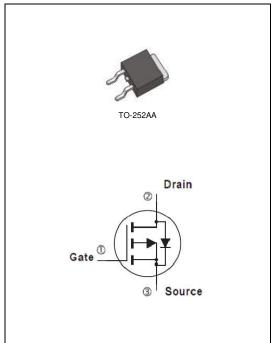
- $R_{DS(ON)}$, V_{GS} @-10V, I_{D} @-10A<12m Ω
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-8A<17.5mΩ
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	-40	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _C =25°C	l _D	-50	A	
	T _C =100°C		-32		
Pulsed Drain Current (Note 1)	T _C =25°C	I_{DM}	-166		
Power Dissipation	T _C =25°C	Po	75	10/	
	T _C =100°C		38	W	
Continuous Drain Current (Note 4)	T _A =25°C	lο	-9	Α	
	T _A =70°C		-7		
Power Dissipation	T _A =25°C	Po	2.4	W	
	T _A =70°C		1.7		
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2	°C/W	
	Junction to Ambient	R _{0JA}	62.5		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.52	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	10	12	mΩ
		V _{GS} =-4.5V, I _D =-8A	-	13.5	17.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	lgss	$V_{GS}=\pm20V$, $V_{DS}=0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =-32V, I _D =-10A, V _{GS} =-4.5V (Note 2,3)	-	23	-	nC
Gate-Source Charge	Qgs		-	8.5	-	
Gate-Drain Charge	Q_{gd}		-	9	-	
Input Capacitance	Ciss	V _{DS} =-25V, V _{GS} =0V,	-	2767	-	pF
Output Capacitance	Coss		-	247	-	
Reverse Transfer Capacitance	Crss	I = IIVIFIZ	-	139	-	
Turn-On Delay Time	td _(on)	. V 00V I- 1A	-	23	-	
Turn-On Rise Time	tr	V_{DS} =-20V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω	-	10	-	ns
Turn-Off Delay Time	td _(off)		-	135	-	
Turn-Off Fall Time	t _f	(**************************************	-	50	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is				-50	Α
Diode Forward Current	IS		-	-	-50	^
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.7	-1	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

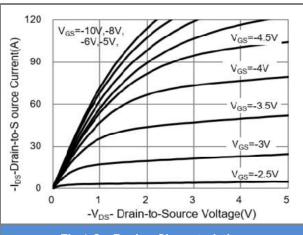


Fig.1 On-Region Characteristics

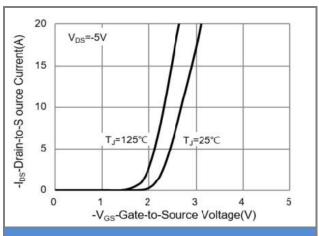


Fig.2 Transfer Characteristics

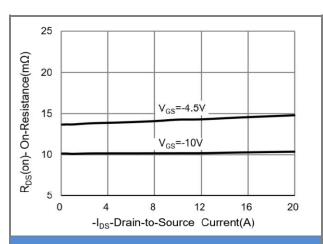


Fig.3 On-Resistance vs. Drain Current

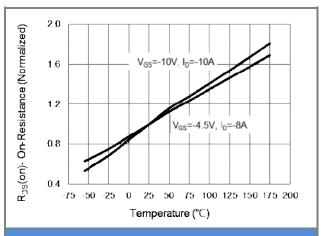


Fig.4 On-Resistance vs. Junction temperature

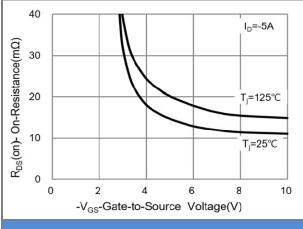


Fig.5 On-Resistance Variation with V_{GS}

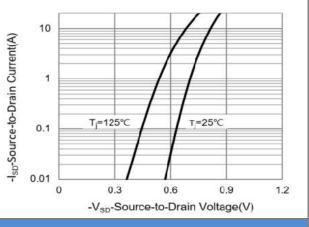


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

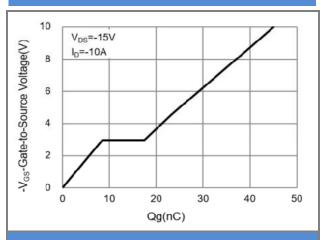


Fig.7 Gate-Charge Characteristics

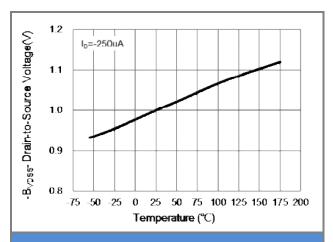


Fig.8 Breakdown Voltage Variation vs. Temperature

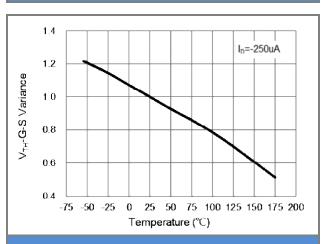


Fig.9 Threshold Voltage Variation with Temperature

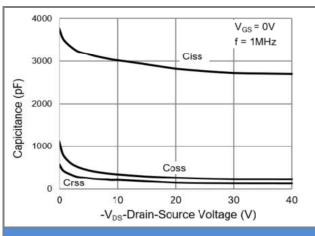


Fig.10 Capacitance vs. Drain-Source Voltage

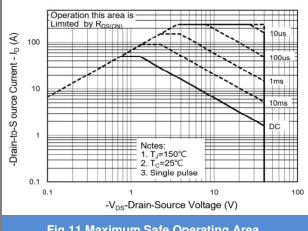


Fig.11 Maximum Safe Operating Area

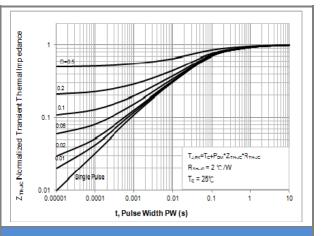


Fig.12 Normalized Thermal Transient Impedance

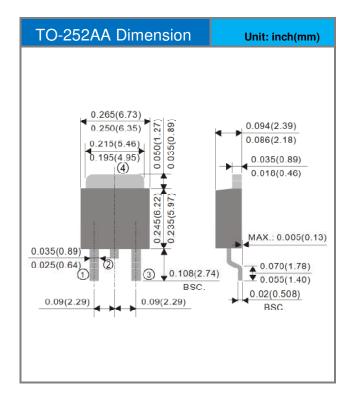


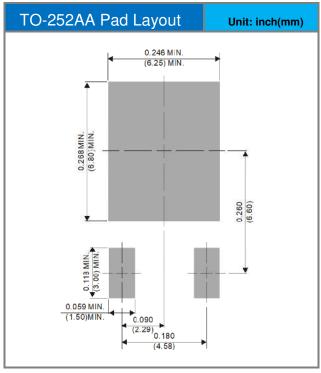


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJD50P04-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D50P04	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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